MURF1620CTG

Switch-mode Power Rectifier

These state-of-the-art devices are designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Ultrafast 35 Nanosecond Recovery Times
- 150°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- Electrically Isolated. No Isolation Hardware Required.
- ESD Rating:
 - ◆ Human Body Model = 3B (> 8 kV)
 - Machine Model = C (> 400 V)
- This is a Pb-Free Package*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



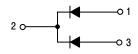
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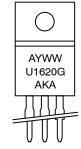
ULTRAFAST RECTIFIER16 AMPERES, 200 VOLTS



ISOLATED TO-220 CASE 221AH



MARKING DIAGRAM



A = Assembly Location
Y = Year

WW = Work Week
U1620 = Device Code
G = Pb-Free Package
AKA = Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping [†]
MURF1620CTG	TO-220 (Pb-Free)	50 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MURF1620CTG

MAXIMUM RATINGS (Per Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
Average Rectified Forward Current Per Diode, (Rated V_R), T_C = 150°C Total Device	I _{F(AV)}	8 16	А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz), T _C = 150°C	I _{FM}	16	А
Non-repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	100	Α
Operating Junction and Storage Temperature	T _J , T _{stg}	- 65 to +150	°C
RMS Isolation Voltage (t = 0.3 second, R.H. \leq 30%, T_A = 25°C) (Note 1)	V _{iso1}	4500	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS (Per Leg)

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	4.2	°C/W
Lead Temperature for Soldering Purposes: 1/8" from the Case for 5 seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS (Per Leg)

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 2) ($i_F = 8.0 \text{ A}, T_C = 150^{\circ}\text{C}$) ($i_F = 8.0 \text{ A}, T_C = 25^{\circ}\text{C}$)	V _F	0.895 0.975	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, $T_C = 150^{\circ}C$) (Rated DC Voltage, $T_C = 25^{\circ}C$)	İR	250 5.0	μА
Maximum Reverse Recovery Time ($I_F = 1.0$ A, $di/dt = 50$ A/ μ s) ($I_F = 0.5$ A, $I_{BEC} = 0.25$ A)	t _{rr}	35 25	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width = $300 \mu s$, Duty Cycle $\leq 2.0\%$.

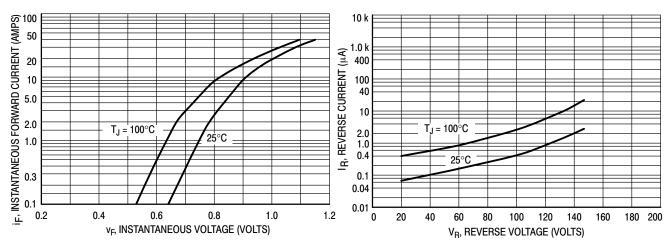


Figure 1. Typical Forward Voltage, Per Leg

Figure 2. Typical Reverse Current, Per Leg*

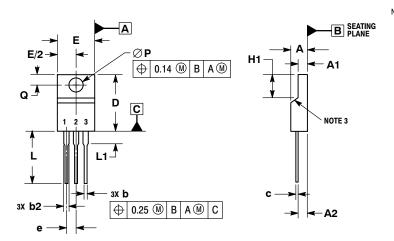
^{1.} Proper strike and creepage distance must be provided.

MURF1620CTG

PACKAGE DIMENSIONS

TO-220 FULLPACK, 3-LEAD

CASE 221AH **ISSUE E**



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.

- CONTOUR UNCONTROLLED IN THIS AREA.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH
 AND GATE PROTRUSIONS. MOLD FLASH AND GATE
 PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
- 5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

	MILLIMETERS	
DIM	MIN	MAX
Α	4.30	4.70
A1	2.50	2.90
A2	2.50	2.90
b	0.54	0.84
b2	1.10	1.40
С	0.49	0.79
D	14.70	15.30
E	9.70	10.30
е	2.54 BSC	
H1	6.70	7.10
L	12.70	14.73
L1		2.10
P	3.00	3.40
Q	2.80	3.20

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